## NSN 5961-00-333-9077

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Between 0.150 inches and 0.300 inches
Terminal Length:
Between 1.000 inches and 1.500 inches
Overall Diameter:
Between 0.115 inches and 0.155 inches
End Application:
Support equipment, b-1 aircraft; sonar signal processing sys, an/sqq-2 (v); helicopter, search and rescue, hh-60h; sonar acoustic
miscellaneous; ticonderoga class cg (47); telephone circuit switch, an/ttc-39; missile, all-weather antiship, harpoon (agm-84); close in
weapon system (ciws-phalanx); helicopter, carrier based asw, sh-60f; los angeles class ssn(688)
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 working peak reverse voltage, peak total value
Current Rating Per Characteristic:
80.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Weapon system essential
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/424 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

**Fiig:** A110a0

No